

KM4111/KM4121 0.2mA, Low Cost, +2.7V & +5V, 35MHz Rail-to-Rail Amplifiers

Features

- 208µA supply current
- 35MHz bandwidth
- Power down to $I_s = 35\mu A$ (KM4121)
- Fully specified at +2.7V and +5V supplies
- Output voltage range: 0.08V to 4.88V; V_s = +5
- Input voltage range: -0.3V to +3.8V; $V_s = +5$
- 27V/µs slew rate
- ±8.5mA linear output current
- ±13mA short circuit output current
- 21nV/√Hz input voltage noise
- Directly replaces MAX4281
- Small package options (SOT23-5 and SOT23-6)

Applications

- Portable/battery-powered applications
- A/D buffer
- Active filters
- Signal conditioning
- Portable test instruments

KM4111/KM4121 Packages

SOT23-5 (KM4111)



SOT23-6 (KM4121)



General Description

The KM4111 (single) and KM4121 (single with disable) are ultra-low power, low cost, voltage feedback amplifiers. These amplifiers use only 208µA of supply current and are designed to operate on +2.7V, +5V, or ±2.5V supplies. The input voltage range extends 300mV below the negative rail and 1.2V below the positive rail.

The KM4111 offers high bipolar performance at a low CMOS price. The KM4111 offers superior dynamic performance with a 35MHz small signal bandwidth and $27V/\mu s$ slew rate. The combination of lowpower, high bandwidth, and rail-to-rail performance make the KM4111 well suited for battery-powered communication/computing systems.



KM4111/KM4121 Electrical Characteristics ($V_s = +2.7V$, G = 2, $R_L = 2k\Omega$ to $V_s/2$, $R_f = 2.5k\Omega$; unless noted)

Case Temperature+25°C+25°CFrequency Domain Response -3dB bandwidth $G = +1, V_0 = 0.05V_{pp}$ $G = +2, V_0 < 0.2V_{pp}$ $G = +1, V_0 = 2V_{pp}$ 28 15 7 7MHz NHz1 1 MHzfull power bandwidth g ain bandwidth product $G = +1, V_0 = 2.02V_{pp}$ 7 728MHz 101Time Domain Response rise and fall time setting time to 0.1% overshoot 2V step, G = -116ns ns ns overshoot 2V step, G = -1ns ns ns overshoot 2V step, G = -1Distortion and Noise Response and harmonic distortion input offset voltage average drift input offset voltage average drift input offset voltage average drift input offset voltage average drift unt off time turn of time	PARAMETERS	CONDITIONS	ТҮР	MIN & MAX	UNITS	NOTES
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$\begin{array}{c c c c c c c c c c c c c c c c c c c $	3rd harmonic distortion	$1V_{pp}$, 100kHz	63		dBc	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $		1Vpp, 100kHz				
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Input voltage noise	>10kHz	23		nV/√Hz	
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$ \begin{array}{c} \mbox{input common mode voltage range} \\ \mbox{common mode rejection ratio} & DC, V_{cm} = 0V \mbox{ to } V_s - 1.5 & -0.3 \mbox{ to } 1.5 & 92 & 65 & dB & 2 \\ \hline \mbox{Output Characteristics} \\ \mbox{output voltage swing} & R_L = 10 \mbox{k} \Omega \mbox{ to } V_s/2 & 0.06 \mbox{ to } 2.62 & 0.2 \mbox{ to } 2.4 & V & 2 \\ \hline \mbox{linear output current} & \pm 8 & \pm 12.5 & & & mA & mA \\ \end{array} $	input resistance					
$\begin{array}{c cccc} \hline common mode rejection ratio \\ \hline output Characteristics \\ output voltage swing \\ linear output current \\ short circuit output current \\ \hline circuit output current \\ \hline common mode rejection ratio \\ \hline DC, V_{cm} = 0V to V_s - 1.5 \\ \hline DC, V_{cm} = 0V to V_$	input capacitance					
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short circuit output current ±12.5 mA		$R_{L} = 2k\Omega \text{ to } V_{s}/2$		0.2 to 2.4	V	2
		-				
power supply operating range $\parallel 2.7 \parallel 2.5$ to $5.5 \parallel V \parallel$	power supply operating range		±12.5 2.7	2.5 to 5.5	MA V	

Min/max ratings are based on product characterization and simulation. Individual parameters are tested as noted. Outgoing quality levels are determined from tested parameters.

NOTES:

1) For G = +1, $R_f = 0$. 2) 100% tested at +25°C.

Absolute Maximum Ratings

Package Thermal Resistance

supply voltage	0 to +6V	Package	${\sf A}_{\sf L}{}^{(\!$	
maximum junction temperatur	e +175°C	5 lead SOT23	256°C/W	
storage temperature range	-65°C to +150°C	6 lead SOT23	230°C/W	
lead temperature (10 sec)	+260°C			
operating temperature range (re	commended) -40°C to +85°C			
input voltage range	+V _s +0.5V; -V _s -0.5V			
internal power dissipation	see power derating curves			

KM4111/KM4121 Electrical Characteristics ($V_s = +5V$, G = 2, $R_L = 2k\Omega$ to $V_s/2$, $R_f = 2.5k\Omega$; unless noted)

PARAMETERS	CONDITIONS	ТҮР	MIN & MAX	UNITS	NOTES
Case Temperature		+25°C	+25°C		
Frequency Domain Response -3dB bandwidth	$\begin{array}{l} G = +1, V_{O} = 0.05 V_{pp} \\ G = +2, V_{O} < 0.2 V_{pp} \\ G = -1, V_{O} = 2 V_{pp} \end{array}$	35 18		MHz MHz	1
full power bandwidth gain bandwidth product	$G = -1, V_0 = 2V_{pp}$	8 20		MHz MHz	
Time Domain Response rise and fall time	0.2V step	13		ns	
settling time to 0.1%	2V step	140		ns	
overshoot	2V step, G = -1	1		%	
slew rate	2V step, G = -1	27		V/μs	
Distortion and Noise Response 2nd harmonic distortion	2V _{pp} , 100kHz	78		dBc	
3rd harmonic distortion	$2V_{pp}$, 100kHz	66		dBc	
THD	2V ^{pp,} 100kHz 2V ^{pp,} 100kHz	65		dB	
input voltage noise	>10kHz	21		nV/√Hz	
DC Performance			_		
input offset voltage average drift		-1.5 20	±5	mV uV/°C	2
input bias current		0.37	1.3	μν/ C	2
average drift		1		nÅ/°C	
input offset current	D.C.	7	130	nA	2
power supply rejection ratio open loop gain	DC	60 62	56 56	dB dB	2 2
quiescent current		208	260	μΑ	2
Disable Characteristics					
turn on time		0.7		μs	
turn off time		4.5		μs	
off isolation quiescent current	1MHz	72 35		dΒ μΑ	
·				μΑ	
Input Characteristics input resistance		>10		MΩ	
input capacitance		1.2		pF	
input common mode voltage range		-0.3 to 3.8		V	
common mode rejection ratio	DC, $V_{cm} = 0V$ to $V_s - 1.5$	95	65	dB	2
Output Characteristics					
output voltage swing	$R_L = 10k\Omega$ to $V_s/2$ $R_L = 2k\Omega$ to $V_s/2$	0.08 to 4.88 0.1 to 4.8	0.2 to 4.7		2
linear output current	$M_{L} = 2KS2 to V_{S}/2$	±8.5	0.2 10 4.7	mA	<u> </u>
short circuit output current		±13		mA	
power supply operating range		5	2.5 to 5.5	V	

Min/max ratings are based on product characterization and simulation. Individual parameters are tested as noted. Outgoing quality levels are determined from tested parameters.

NOTES:

1) For G = +1, $R_{f} = 0$. 2) 100% tested at +25°C.

$KM4111/KM4121 \ Performance \ Characteristics \ (V_s=+5V, \ G=2, \ R_L=2k\Omega \ to \ V_s/2, \ R_f=2.5k\Omega; \ unless \ noted)$





$KM4111/KM4121 \ Performance \ Characteristics \ (V_s=+5V, G=2, R_L=2k\Omega \ to \ V_s/2, R_f=2.5k\Omega; \ unless \ noted)$













Large Signal Pulse Response V_s = +5V



General Description

The KM4111 is a single supply, general purpose, voltagefeedback amplifier fabricated on a complementary bipolar process. The KM4111 offers 35MHz unity gain bandwidth, $27V/\mu s$ slew rate, and only $208\mu A$ supply current. It features a rail-to-rail output stage and is unity gain stable.

The design utilizes a patent pending topology that provides increased slew rate performance. The common mode input range extends to 300mV below ground and to 1.2V below V_s . Exceeding these values will not cause phase reversal. However, if the input voltage exceeds the rails by more than 0.5V, the input ESD devices will begin to conduct. The output will stay at the rail during this overdrive condition.

The design uses a Darlington output stage. The output stage is short circuit protected and offers "soft" saturation protection that improves recovery time.

The typical circuit schematic is shown in Figure 1.



Figure 1: Typical Configuration

Enable/Disable Function (KM4121)

The KM4121 offers an active-low disable pin that can be used to lower its supply current. Leave the pin floating to enable the part. Pull the disable pin to the negative supply (which is ground in a single supply application) to disable the output. During the disable condition, the nominal supply current will drop to below 40μ A and the output will be at high impedance with about 2pF capacitance.

Power Dissipation

The maximum internal power dissipation allowed is directly related to the maximum junction temperature. If the maximum junction temperature exceeds 150°C, some reliability degradation will occur. If the maximum junction temperature exceeds 175°C for an extended time, device failure may occur.

The KM4111 is short circuit protected. However, this may not guarantee that the maximum junction temperature (+150°C) is not exceeded under all conditions. Follow the maximum power derating curves shown in Figure 2 to ensure proper operation.



Figure 2: Power Derating Curves

Overdrive Recovery

For an amplifier, an overdrive condition occurs when the output and/or input ranges are exceeded. The recovery time varies based on whether the input or output is overdriven and by how much the ranges are exceeded. The KM4111 will typically recover in less than 20ns from an overdrive condition. Figure 3 shows the KM4111 in an overdriven condition.



Figure 3: Overdrive Recovery

Driving Capacitive Loads

A small series resistance (R_s) at the output of the amplifier, illustrated in Figure 4, will improve stability and settling performance.



Figure 4: Typical Topology for driving a capacitive load

Layout Considerations

General layout and supply bypassing play major roles in high frequency performance. Fairchild has evaluation boards to use as a guide for high frequency layout and to aid in device testing and characterization. Follow the steps below as a basis for high frequency layout:

- Include 6.8µF and 0.01µF ceramic capacitors
- Place the 6.8µF capacitor within 0.75 inches of the power pin
- Place the 0.01µF capacitor within 0.1 inches of the power pin
- Remove the ground plane under and around the part, especially near the input and output pins to reduce parasitic capacitance
- Minimize all trace lengths to reduce series inductances

Refer to the evaluation board layouts shown in Figure 6 for more information.

Evaluation Board Information

The following evaluation boards are available to aid in the testing and layout of this device:

Eval Board	Description	Products	
KEB002	Single Channel, Dual Supply 5 & 6 lead SOT23	KM4111IT5, KM4121IT6	

Evaluation board schematics and layouts are shown in Figure 5 and Figure 6.

The KEB002 evaluation board is built for dual supply operation. Follow these steps to use the board in a single supply application:

- 1. Short -V_s to ground
- 2. Use C3 and C4, if the $-V_s$ pin of the KM4111 or KM4121 is not directly connected to the ground plane.



Figure 5: Evaluation Board Schematic

KM4111/KM4121 Evaluation Board Layout



Figure 6a: KEB002 (top side)



Figure 6b: KEB002 (bottom side)



KM4111/KM4121 Package Dimensions

SOT23-5







SYMBOL	MIN	MAX	
A	0.90	1.45	
A1	0.00	0.15	
A2	0.90	1.30	
b	0.25	0.50	
С	0.09	0.20	
D	2.80	3.10	
E	2.60	3.00	
E1	1.50	1.75	
L	0.35	0.55	
е	0.95 ref		
e1	1.90 ref		
α	0°	10°	

NOTE:

NOTE:

All dimensions are in millimeters.
Foot length measured reference to flat foot surface parallel to DATUM 'A' and lead surface.
Package outline exclusive of mold flash & metal burr.
Package outline inclusive of solder plating.
Comply to EIAJ SC74A.
Package ST 0003 REV A supercedes SOT-D-2005 REV C.

SOT23-6



A2



SYMBOL	MIN	MAX	
A	0.90	1.45	
A1	0.00	0.15	
A2	0.90	1.30	
b	0.25	0.50	
С	0.09	0.20	
D	2.80	3.10	
E	2.60	3.00	
E1	1.50	1.75	
L	0.35	0.55	
е	0.95 ref		
e1	1.90 ref		
α	0°	10°	

A1

NOTE: 1. All dimensions are in millimeters. Construction of the source of the fact of the fact of the fact one parallel to DATUM 'A' and lead surface. 3. Package outline exclusive of mold flash & metal burr. 4. Package outline inclusive of solder plating. 5. Comply to EIAJ SCT4A. 6. Package ST 0004 REV A supercedes SOT-D-2006 REV C.

Ordering Information

Model	Part Number	Package	Container	Pack Qty
KM4111	KM4111IT5	SOT23-5	Partial Reel	<3000
KM4111	KM4111IT5TR3	SOT23-5	Reel	3000
KM4121	KM4121IT6	SOT23-6	Partial Reel	<3000
KM4121	KM4121IT6TR3	SOT23-6	Reel	3000

Temperature range for all parts: -40°C to +85°C

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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.